USL3533K Preliminary CMOS IC

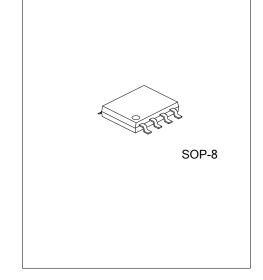
NON-ISOLATED BUCK OFFLINE LED DRIVER

■ DESCRIPTION

The UTC **USL3533K** is a high performance, high precision and low cost constant current LED driver for non-isolated buck application. The device operates in critical conduction mode and is suitable for 85V~265V universal input offline LED lighting. It operates in critical conduction mode, the output current does not change with the inductance and LED output voltage.

The UTC **USL3533K** integrates a 500V power MOSFET. It can achieve excellent constant current performance with very few external components, so the system cost and size are minimized.

The UTC **USL3533K** offers rich protection functions to improve the system reliability, including LED open circuit protection, LED short circuit protection, V_{CC} under voltage protection, CS resistor short circuit protection and thermal regulation function.

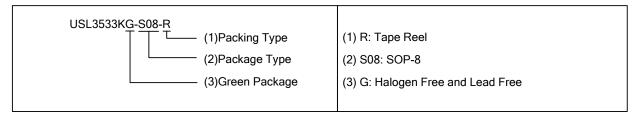


■ FEATURES

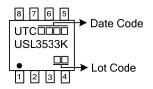
- * Critical conduction mode operation
- * Internal 500V Power MOSFET
- * Ultra low operating current
- * No auxiliary winding
- * ±5% LED output current accuracy
- * LED short protection
- * LED open protection
- * V_{CC} under voltage protection
- * Current sensing resistor short protection
- * Thermal regulation function

■ ORDERING INFORMATION

Ordering Number	Package	Packing
USL3533KG-S08-R	SOP-8	Tape Reel

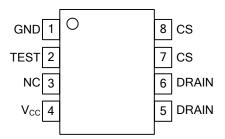


■ MARKING



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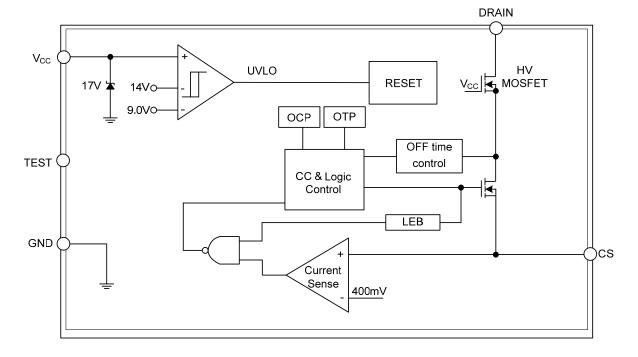
■ PIN CONFIGURATION



■ PIN DESCRIPTION

PIN NO.	PIN NAME	DESCRIPTION
1	GND	Ground
2	TEST	For Test. Should be floating or connected to GND (Pin1)
3	NC	No connection. Should be connected to GND (Pin1)
4	V _{CC}	Power supply pin
5, 6	DRAIN	Internal HV Power MOSFET Drain.
7, 8	CS	Current sense pin. Connect a sense resistor between this pin and GND pin.

■ BLOCK DIAGRAM



■ ABSOLUTE MAXIMUM RATING

PARAMETER	SYMBOL	RATINGS	UNIT
V _{CC} Pin Maximum Sink Current	I _{CC MAX}	5	mA
Internal HV MOSFET Drain Voltage	DRAIN	-0.3~500	V
Current Sense Pin Input Voltage	CS	-0.3~6	V
Over-Voltage Setting Pin Voltage	TEST	-0.3~6	V
Power Dissipation	P_{D}	0.45	W
Junction Temperature	TJ	-40~+150	°C
Storage Temperature	T _{STG}	-55~+150	°C

Note: Absolute maximum ratings are those values beyond which the device could be permanently damaged.

Absolute maximum ratings are stress ratings only and functional device operation is not implied.

■ RECOMMENDED OPERATION CONDITIONS

PARAMETER	SYMBOL	RATINGS	UNIT
Output LED Current @ V _{OUT} =72V (Input Voltage 176V~265V)	I _{LED1}	280	mA
Output LED Current @ V _{OUT} =36V (Input Voltage 176V~265V)	I _{LED2}	350	mA
Minimum LED Loading Voltage	V _{LED min}	>15	V

■ THERMAL RESISTANCES CHARACTERISTICS

PARAMETER	SYMBOL	RATING	UNIT
Junction to Ambient	θ_{JA}	150	°C/W

■ **ELECTRICAL CHARACTERISTICS** (Notes 1, 2) (Unless otherwise specified, V_{CC}=14V and T_A=25°C)

V_{CC} Clamp Voltage V_{CC} CLAMP V_{CC} CLAMP V_{CC} Turn On Threshold V_{CC} Turn On Threshold V_{CC} On V_{CC} Rising V_{CC} Turn Off Threshold V_{CC} On V_{CC} Rising V_{CC} Turn Off Threshold V_{CC} Over Falling V_{CC} Startup Current V_{CC} Startup Current V_{CC} Operating V								
V_{CC} Clamp Voltage V_{CC} CLAMP V_{CC} CLAMP V_{CC} Turn On Threshold V_{CC} Turn On Threshold V_{CC} On V_{CC} Rising V_{CC} Turn Off Threshold V_{CC} Turn Off Threshold V_{CC} UVLO V_{CC} Falling V_{CC} Startup Current V_{CC} Startup Current V_{CC} Operating V_{CC} Operati	PARAMETER	SYMBOL	TEST CONDITIONS	MIN	TYP	MAX	UNIT	
$\begin{array}{c ccccccccccccccccccccccccccccccccccc$	SUPPLY VOLTAGE SECTION							
V_{CC} Turn On Threshold V_{CC} ON V_{CC} Rising V_{CC} Turn Off Threshold V_{CC} Turn Off Threshold V_{CC} UVLO V_{CC} Falling V_{CC} Startup Current V_{CC} Startup Current V_{CC} Operating V_{CC}	V _{CC} Clamp Voltage	V_{CC_CLAMP}	1mA		16.8		V	
V_{CC} Turn Off Threshold V_{CC} UVLO V_{CC} Falling 9 V_{CC} VCC Startup Current I_{ST} $V_{CC} = V_{CC-ON} - 1V$ 180 280 μ A V_{CC} Operating Current I_{OP} $F_{OP} = 70$ KHz 200 300 μ A V_{CC} Operating Current I_{OP} I_{OP} I_{OP} $I_{OP} = 70$ KHz I_{OP} $I_{OP} = 70$ KHz	V _{CC} Turn On Threshold		V _{CC} Rising		13.8		V	
V _{CC} Operating CurrentI _{OP} F _{OP} =70KHz200300μACURRENT SENSE SECTIONThreshold Voltage for Peak Current LimitV _{CS_peak} 390400410mVThreshold Voltage for Peak Current Limit When Output ShortV _{CS_SHORT} Output Short200mVLeading Edge Blanking Time for Current Sense T_{LEB} 300nsSwitch Off Delay Time T_{DELAY} 200nsINTERNAL TIME CONTROL SECTIONMinimum OFF Time T_{OFF_MIN} 3μsMaximum OF Time T_{ON_MAX} 35μsMaximum On Time T_{ON_MAX} 35μsMOSFET SECTIONStatic Drain-source On-resistance R_{DS_ON} $V_{GS}=15V/I_{DS}=0.4A$ 3.0 Ω Drain-Source Breakdown Voltage BV_{DSS} $V_{GS}=0V/I_{DS}=250\mu A$ 500 V Power MOSFET Drain Leakage Current I_{DSS} $V_{GS}=0V/V_{DS}=500V$ 1 μ THERMAL REGULATION SECTION	V _{CC} Turn Off Threshold		V _{CC} Falling		9		V	
CURRENT SENSE SECTION Threshold Voltage for Peak Current Limit V_{CS_peak} 0 0 0 0 0 0 0 0 0 0	V _{CC} Startup Current	I _{ST}	V _{CC} = V _{CC-ON} - 1V		180	280	μA	
Threshold Voltage for Peak Current Limit V_{CS_peak} V_{CS_SHORT} Output Short V	V _{CC} Operating Current	I _{OP}	F _{OP} =70KHz		200	300	μA	
Threshold Voltage for Peak Current Limit When Output Short V_{CS_SHORT} Output Shor	CURRENT SENSE SECTION				_	_	_	
Threshold Voltage for Peak Current Limit When Output Short V_{CS_SHORT} Output Shor	Threshold Voltage for Peak Current Limit	V_{CS_peak}		390	400	410	mV	
Output Short Leading Edge Blanking Time for Current Sense T_{LEB} 300 ns Switch Off Delay Time 200 ns INTERNAL TIME CONTROL SECTION Minimum OFF Time T_{OFF_MIN} 3 μ_S Maximum OFF Time T_{OFF_MAX} 220 μ_S Maximum On Time T_{ON_MAX} 35 μ_S MoSFET SECTION Static Drain-source On-resistance R_{DS_ON} V_{GS} =15V/ I_{DS} =0.4A 3.0 Ω Drain-Source Breakdown Voltage R_{DS}	Threshold Voltage for Peak Current Limit When		Output Chart		200		m\/	
Switch Off Delay Time T_{DELAY} 200 ns INTERNAL TIME CONTROL SECTION Minimum OFF Time T_{OFF_MIN} 3 μ_S Maximum OFF Time T_{OFF_MAX} 220 μ_S Maximum On Time T_{ON_MAX} 35 μ_S MOSFET SECTION Static Drain-source On-resistance R_{DS_ON} V_{GS} =15 V / I_{DS} =0.4A 3.0 Ω Drain-Source Breakdown Voltage R_{DS} R	Output Short	VCS_SHORT	Output Short		200		mv	
INTERNAL TIME CONTROL SECTION Minimum OFF Time T_{OFF_MIN} 3 μs Maximum OFF Time T_{OFF_MAX} 220 μs Maximum On Time T_{ON_MAX} 35 μs MOSFET SECTION Static Drain-source On-resistance R_{DS_ON} V_{GS} =15V/ I_{DS} =0.4A 3.0 Ω Drain-Source Breakdown Voltage BV_{DSS} V_{GS} =0V/ I_{DS} =250μA 500 V Power MOSFET Drain Leakage Current I_{DSS} V_{GS} =0V/ V_{DS} =500V 1 μA THERMAL REGULATION SECTION	Leading Edge Blanking Time for Current Sense	T_LEB			300		ns	
Minimum OFF Time T_{OFF_MIN} 3 μs Maximum OFF Time T_{OFF_MAX} 220 μs Maximum On Time T_{ON_MAX} 35 μs MOSFET SECTION Static Drain-source On-resistance R_{DS_ON} $V_{GS}=15V/I_{DS}=0.4A$ 3.0 Ω Drain-Source Breakdown Voltage BV_{DSS} $V_{GS}=0V/I_{DS}=250\mu A$ 500 V Power MOSFET Drain Leakage Current I_{DSS} $V_{GS}=0V/V_{DS}=500V$ 1 μA THERMAL REGULATION SECTION	Switch Off Delay Time	T_{DELAY}			200		ns	
Maximum OFF Time T_{OFF_MAX} 220μsMaximum On Time T_{ON_MAX} 35μsMOSFET SECTIONStatic Drain-source On-resistance R_{DS_ON} $V_{GS}=15V/I_{DS}=0.4A$ 3.0 Ω Drain-Source Breakdown Voltage BV_{DSS} $V_{GS}=0V/I_{DS}=250\mu A$ 500 V Power MOSFET Drain Leakage Current I_{DSS} $V_{GS}=0V/V_{DS}=500V$ 1 μA THERMAL REGULATION SECTION	INTERNAL TIME CONTROL SECTION	-			-	-	_	
Maximum On Time T_{ON_MAX} 35 μs MOSFET SECTION Static Drain-source On-resistance R_{DS_ON} V_{GS} =15V/ I_{DS} =0.4A 3.0 Ω Drain-Source Breakdown Voltage R_{DSS}	Minimum OFF Time	T _{OFF_MIN}			3		μs	
Maximum On Time T_{ON_MAX} 35μsMOSFET SECTION	Maximum OFF Time	T_{OFF_MAX}			220		μs	
Static Drain-source On-resistance R_{DS_ON} V_{GS} =15V/ I_{DS} =0.4A 3.0 Ω Drain-Source Breakdown Voltage BV_{DSS} V_{GS} =0V/ I_{DS} =250 μ A 500 V Power MOSFET Drain Leakage Current I_{DSS} V_{GS} =0V/ V_{DS} =500V 1 μ A THERMAL REGULATION SECTION	Maximum On Time				35		μs	
Drain-Source Breakdown Voltage BV_{DSS} V_{GS} =0V/ I_{DS} =250 μ A 500 V Power MOSFET Drain Leakage Current I_{DSS} V_{GS} =0V/ V_{DS} =500V 1 μ A THERMAL REGULATION SECTION	MOSFET SECTION							
Power MOSFET Drain Leakage Current I _{DSS} V _{GS} =0V/V _{DS} =500V 1 μA THERMAL REGULATION SECTION	Static Drain-source On-resistance	R _{DS_ON}	V _{GS} =15V/I _{DS} =0.4A		3.0		Ω	
THERMAL REGULATION SECTION	Drain-Source Breakdown Voltage	BV _{DSS}	V _{GS} =0V/I _{DS} =250μA	500			V	
	Power MOSFET Drain Leakage Current	I _{DSS}	V _{GS} =0V/V _{DS} =500V			1	μA	
Thermal Regulation Temperature T _{REG} 150 °C	THERMAL REGULATION SECTION							
	Thermal Regulation Temperature	T _{REG}			150		°C	

Notes: 1. Production testing of the chip is performed at 25°C.

^{2.} The maximum and minimum parameters specified are guaranteed by test, the typical value are guaranteed by design, characterization and statistical analysis.



■ APPLICATION INFORMATION

The UTC **USL3533K** is a high performance non-isolated Buck converter specially designed for LED lighting. The device integrates a 500V power MOSFET. With very few external components, the converter achieves excellent constant current control. And it does not need auxiliary winding for powering the IC or voltage sensing, thus the system size and cost is greatly reduced.

Start Up

When system powered up, the V_{CC} pin capacitor is charged up by the start up resistor. When the V_{CC} pin voltage reaches the start up threshold, the internal circuits start operating. The UTC **USL3533K** integrates a 17V zener diode to clamp the V_{CC} voltage.

Constant Current Control

Cycle by Cycle current sense is adjusted in UTC **USL3533K**, the CS pin is connected to the current sense comparator, and the voltage on CS pin is compared with the internal 400mV reference voltage. The MOSFET will be switched off when the voltage on CS pin reaches the Peak Current threshold. The CS comparator includes a 350ns leading edge blanking time. After the MOSFET switched off, the OFF time controller would open the MOSFET again at time up. At that moment, CS pin voltage is 0mV usually.

The Delta inductor current is given by:

$$I_{PK} = \frac{400}{R_{CS}} (mA)$$

Where, R_{CS} is the current sense resistor value.

The current in LED can be calculated by the equation:

$$I_{LED} = \frac{I_{PK}}{2} = \frac{200}{R_{CS}} (mA)$$

Where, IPK is the Peak current of the inductor.

Inductor Selection

The UTC **USL3533K** works under inductor current critical conduction mode. When the power MOFET is switched on, the current in the inductor rises up from zero, the on time of the MOSFET can be calculated by the equation:

$$t_{on} = \frac{L \times I_{PK}}{V_{IN} - V_{LED}}$$

Where,

L is the inductance value

 V_{IN} is the DC bus voltage after the rectifier bridge

V_{LED} is the voltage on the LED

After the power MOSFET is switched off, the current in the inductor decreases. When the inductor current reaches zero, the power MOSFET is turned on again by IC internal logic. The off time of the MOSFET is given by:

$$t_{off} = \frac{L \times I_{PK}}{V_{LED}}$$

The inductance can be calculated by the equation:

$$L = \frac{V_{\mathit{LED}} \times (V_{\mathit{IN}} - V_{\mathit{LED}})}{freq \times I_{\mathit{PK}} \times V_{\mathit{IN}}}$$

The freq is the system switching frequency, which is proportional to the input voltage. So the minimum switching frequency is set at lowest input voltage, and the maximum switching frequency is set at highest input voltage.

The minimum and maximum off time of UTC **USL3533K** is set at $4.5\mu s$ and $240\mu s$, respectively. Referring to the equation of t_{OFF} calculation, if the inductance is too small, the t_{OFF} may be smaller than the minimum off time, system will operate in discontinuous conduction mode and the output current will be smaller than the designed value. If the inductance is too large, the t_{OFF} may be larger than the maximum off time, the outputt current will not be constant follow design value. So it is important to choose a proper inductance, we recommend user to regulate the inductance value for 70KHz application.

■ APPLICATION INFORMATION (Cont.)

Protection Function

The UTC **USL3533K** offers rich protection functions to improve the system reliability, including LED open/short protection, CS resistor short protection, V_{CC} under voltage protection, thermal regulation.

When the LED short circuit is detected, the system works at low frequency (about 5kHz), and the CS pin turn off threshold is reduced to 200mV. So the system power consumption is very low. At some catastrophic fault condition, such as CS resistor shorted or inductor saturated, the internal fast fault detection circuit will be triggered, the system stops switching immediately.

After the system enters into fault condition, the V_{CC} voltage will decrease until it reaches the UVLO threshold, then the system will re-start again. If the fault condition is removed, the system will recover to normal operation.

Thermal Regulation

The UTC **USL3533K** integrates thermal regulation function. When the system is over temperature, the output current is gradually reduced; the output power and thermal dissipation are also reduced. The system temperature is regulated and the system reliability is improved. The thermal regulation temperature is set to 150°C internally.

PCB Layout

The following rules should be followed in UTC USL3533K PCB layout:

Bypass Capacitor

The bypass capacitor on V_{CC} pin should be as close as possible to the V_{CC} Pin and GND pin.

TEST Pin

The TEST Pin should be floating or connected to GND (pin1).

Ground Path

The power ground path for current sense should be short, and the power ground path should be separated from small signal ground path before connecting to the negative node of the bulk capacitor.

The Area of Power Loop

The area of main current loop should be as small as possible to reduce EMI radiation, such as the inductor, the power MOSFET, the output diode and the bus capacitor loop.

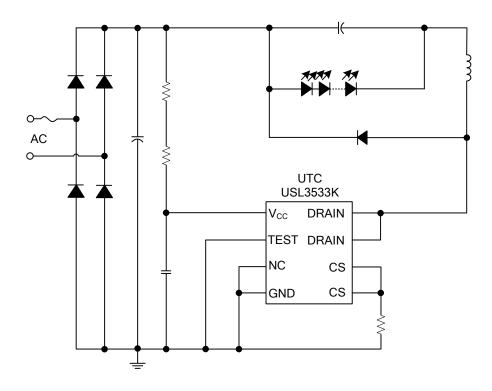
NC pin

The NC pin should be connected to GND (pin1).

Drain Pin

To increase the copper area of DRAIN pin for better thermal dissipation. However too large copper area may compromise EMI performance.

TYPICAL APPLICATION CIRCUIT



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